PATENT APPLICATION



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the	e Application of					
David-A	Alan-FORD et-al-					
Applica	ation No.: 09/859,532					
Filed:	May 18, 2001	Docket No.: 109528				
For:	SINGLE CRYSTAL SEED ALLO	Y				
CLAIM FOR PRIORITY						
	or of the U.S. Patent and Trademark agton, D.C. 20231	Office				
Sir:						
foreign	_	e following prior foreign application filed in the following above-identified patent application and the priority ned:				
	X is filed herewith.	copy of said original foreign application: rent Application No filed				
35 U.S.C		pplication be marked to indicate that the requirements of the Patent and Trademark Office kindly acknowledge Respectfully submitted,				
•	- 4	Mongalanda, James A. Oliff				

Thomas J. Pardini Registration No. 30,411

Registration No. 27,075

JAO:TJP/cmm

Date: September 17, 2001

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I also certify that the attached copy of the request for grant of a Patent (Form 1/77) bears an amendment, effected by this office, following a request by the applicant and agreed to by the Comptroller-General.

In accordance with the Patents (Companies Re-registration) Rules 1982, if a company named in this certificate and any accompanying documents has re-registered under the Companies Act 1980 with the same name as that with which it was registered immediately before re-registration save for the substitution as, or inclusion as, the last part of the name of the words "public limited company" or their equivalents in Welsh, references to the name of the company in this certificate and any accompanying documents shall be treated as references to the name with which it is so re-registered.

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Dated 22 May 2001

OLIFF & BERRIDGE, PLC P.O. BOX 19928 P.O. BOX 19928
ALEXANDRIA, VA 22320
(703) 836-6400
APPLICANT: David Alan FORD et al.
APPLICATION NO.: 09/859,532
FILED: May 18, 2001
FOR: SINGLE CRYSTAL SEED ALLOY
ATTORNEY DOCKET NO.: 109528

ents Form 1/77 tents Act 1977 ule 16 P01/7700 0.00-0012185.5 2 0 MAY 2000 Request for grant of a patent (See the notes on the back of this form. You can also get The Patent Office an explanatory leaflet from the Patent Office to bely NEWPORT Cardiff Road you fill in this form) Newport Gwent NP9 1RH Your reference PAT/VJB/2785 2. Patent application number 0012185.5 **2** 0 MAY 2000 (The Patent Office will fill in this part) 3. Full name, address and postcode of the or of ROLLS-ROYCE plc each applicant (underline all surnames) 65 BUCKINGHAM GATE LONDON 30100002 SW1E 6AT Patents ADP number (if you know it) **GREAT BRITAIN** If the applicant is a corporate body, give the **GREAT BRITAIN** country/state of its incorporation Title of the invention SINGLE CRYSTAL SEED ALLOY 5. Name of your agent (if you have one) INTELLECTUAL PROPERTY DEPT EW 1-5 "Address for service" in the United Kingdom .J∠Ś-ROYCĘ∕ølc to which all correspondence should be sent РОВОХ (including the postcode) ARE a Co HASELT INE PILTON IMPERIAL HOUSE BRISTOL BS34 7QE KINGSWAY WCZB 6UB Patents ADP number (if you know it) FCL 6. If you are declaring priority from one or more 22/5/0/Country Priority application number Date of filing earlier patent applications, give the country (if you know it) (day / month / year) and the date of filing of the or of each of these earlier applications and (if you know it) the or each application number

 If this application is divided or otherwise derived from an earlier UK application, give the number and the filing date of the earlier application

Number of earlier application

Date of filing (day / month / year)

8. Is a statement of inventorship and of right

YES

- to grant of a patent required in support of this request? (Answer 'Yes' if:
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Priority documents	0		
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Statement of inventorship and right to grant of a patent (Patents Form 7/77)	NO		
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Request for substantive examination (Patents Form 10/77)	NO		
Any other documents (please specify)	NO		
11.	I/We reque	est the grant of a patent of	on the basis of this application.
	Signature	16.	Date 19 MAY 2000
12. Name and daytime telephone number of	MR V J BIRE	0117 979 7137	

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18 MAY 2001 The Patent Office

NEWPORT / Cardiff Road

Statement of inventorship and of right to grant of a patent

Newport Gwent NP9 1RH HL78766/000 1. Your reference 2. Patent application number 0012185.5 (if you know it) Rolls-Royce plc 3. Full name of the or of each applicant Title of the invention SINGLE CRYSTAL SEED ALLOY 5. State how the applicant(s) derived the right from the inventor(s) to be granted a patent By virtue of the inventors' contract of employment 6. How many, if any, additional Patent Forms None 7/77 are attached to this form? (See note (c)) 7. I/We believe that the person(s) named over the page (and on any extra copies of this form) is/are the inventor(s) of the invention which the above patent application relates to. Signature Date 17 May 2001 8. Name and daytime telephone number of Mr. J.R.A.M. Cheyne [0117] 9103200 person to contact in the United Kingdom

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Enter the full names, addresses and postcodes of the inventors in the boxes and underline the surnames	David Alan <u>Ford</u> 220 Mendip Road, Yatton, Bristol BS49 4DG United Kingdom
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	Anthony David Hill 14 Guernsey Avenue, Brislington, Bristol BS4 4SH United Kingdom
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SINGLE CRYSTAL SEED ALLOY

This invention concerns the composition of a metal alloy suitable for use as single crystal seeds.

Components cast as single crystals, using the process of directional solidification, generate a crystal atomic structure related to the growth of preferred crystal planes. In nickel base superalloys the resultant crystal has a structure determined by growth of the <001> crystal planes. This structure is aligned in the direction of solidification which is normally along the principal geometric axis of the component e.g. a gas turbine engine blade aerofoil.

In certain cases there are applications for components with crystal orientations different to the <001> produced under normal solidification conditions. Such applications include nozzle guide vanes and turbine blades requiring control of material rigidity.

To produce a crystal structure aligned in a direction other than the preferred solidification growth direction it is established practice to solidify from a seed crystal which has the required crystal structure. Solidification from these seeds is by epitaxial growth in which the molten superalloy solidifies directly from a partially melted seed crystal made from the same or equivalent superalloy as the cast component.

A drawback encountered with this known method of determining crystal growth direction during solidification is that a high level of castings are rejected because the seed crystals when partially molten are liable to generate unwanted oxide films which interrupt epitaxial growth of the single crystal and cause further crystals to solidify in which the atomic orientations are randomly distributed.

(III)

The present invention has for a principal objective to overcome this drawback by providing a formulation of an alloy suitable for in single crystal seeds and which does not produce oxide films under the directional solidification conditions used for the casting of superalloys.

According to the present invention there is provided an alloy composition suitable for use as a single crystal seed comprising a nickel superalloy containing in the proportion of 5 to 50 weight % a further metal selected from the Transition Series of elements in Period VI of the Periodic Table of Elements.

Alloy compositions in accordance with the present invention which have been investigated and found to be useful included a nickel/tungsten alloy containing tungsten in the range 5-40 weight %. However, this range of alloys was considered to be unsuitable for conventional directional solidification due to their high thermal conductivity, which made it difficult to control the rate of cooling during withdrawal from the single crystal casting furnace through its temperature transition zone.

The compositions investigated also included nickel/tantalum alloys containing tantalum in the range 10-30 weight %. A particularly successful alloy contained 20% tantalum which solidifies at about 1400°C and was found to be an effective seed alloy for the super alloy CMSX4. Tantalum levels of around 30% solidify at 1360°C and are appropriate for single crystal alloys with melting points of around 1350°C.

These compositions have melting temperatures appropriate for the majority of superalloys and have the added advantage of narrow solidification ranges which reduce the potential for secondary crystal nucleation during solidification.

CLAIMS

- A single crystal seed alloy composition comprising nickel superalloy containing in the proportion of 5 to 40 weight % a further metal selected from the Transition Series of elements in Period VI of the Periodic Table of Elements.
- A single crystal seed alloy composition as claimed in claim 1 wherein the further metal comprises tungsten in the range 5-40 weight %.
- A single crystal seed alloy composition as claimed in claim 1 wherein the further metal comprises tantalum in the range 5-50 weight %.
- 4 A single crystal seed alloy substantially as hereinbefore described.

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